

SUPER FAST RECTIFIERS

VOLTAGE RANGE: 50 --- 600 V

CURRENT: 5.0 A

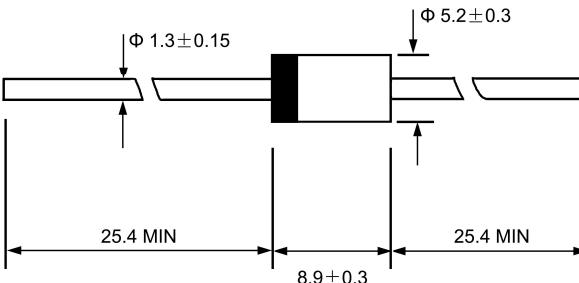
FEATURES

- ◇ Low cost
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-27, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 1.15 grams
- ◇ Mounting position: Any

DO - 27



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

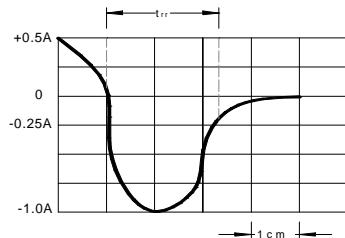
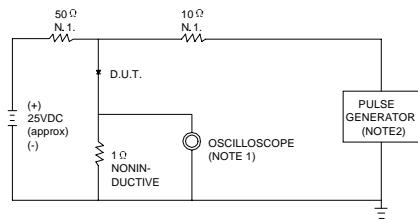
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

	SYMBOLS	SF51	SF52	SF53	SF54	SF55	SF56	SF58	UNITS			
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	600	VOLTS			
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	420	VOLTS			
Maximum DC blocking voltage	V _{DC}	50	100	150	200	300	400	600	VOLTS			
Maximum average forward rectified current 0.375" (9.5mm) lead length at TA=55°C	I _(AV)	5.0						Amps				
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150.0						Amps				
Maximum instantaneous forward voltage at 5.0A	V _F	0.95			1.25			Volts				
Maximum DC reverse current TA=25°C at rated DC blocking voltage TA=100°C	I _R	10.0			50.0			uA				
Maximum reverse recovery time (NOTE 1)	t _{rr}	35						ns				
Typical junction capacitance (NOTE 2)	C _J	100.0			50.0			pF				
Typical thermal resistance (NOTE 3)	R _{qJA}	30.0						°C/W				
Operating junction and storage temperature range	T _{J,T_{STG}}	-65 to +150						°C				

NOTE: 1. Measured with I_F=0.5A, I_R=1A, I_{rr}=0.25A.

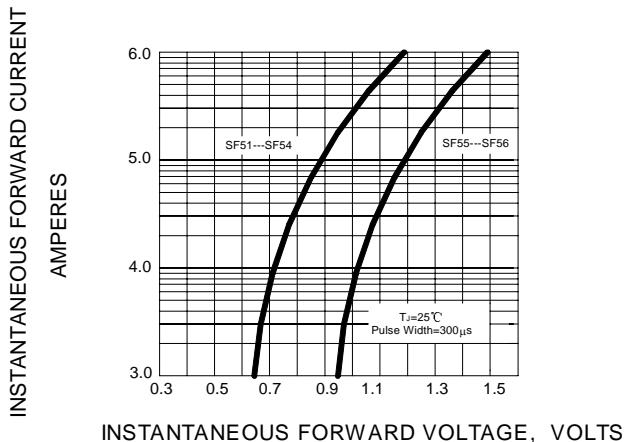
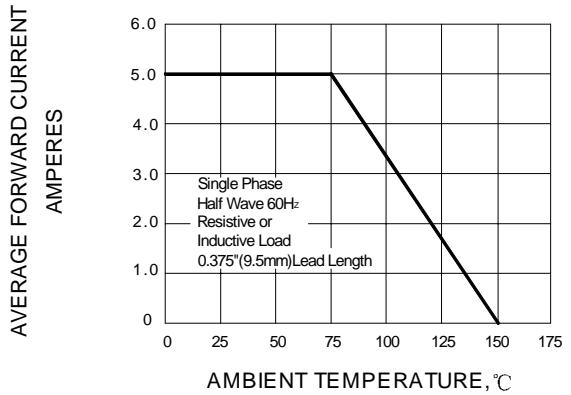
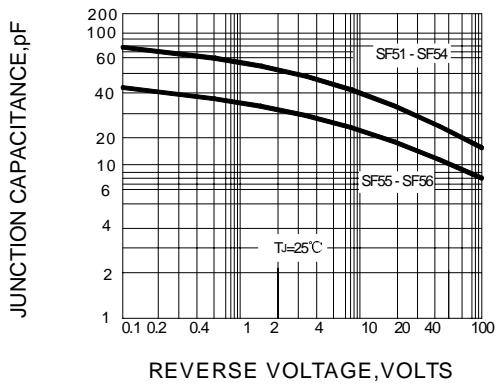
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

NOTES:
1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1MΩ .22pF.
2.RISE TIME = 10ns MAX.SOURCE IMPEDANCE=50 Ω.

SET TIME BASE FOR 10 ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC**FIG.3 -- FORWARD DERATING CURVE****FIG.4 -- TYPICAL JUNCTION CAPACITANCE****FIG.5 -- PEAK FORWARD SURGE CURRENT**